



MP7AN65E

主要参数 MAIN CHARACTERISTICS

I_D	7A
V_{DSS}	650V
$R_{dson-max}$ ($V_{GS}=10V$)	1.25 Ω
Q_g-Typ	20nC

用途

- 高频开关电源
- 电子镇流器
- LED 电源

产品特性

- 低栅极电荷
- 低 C_{rss} (典型值 4.4pF)
- 开关速度快
- 产品全部经过雪崩测试
- 高抗 dv/dt 能力
- RoHS 产品

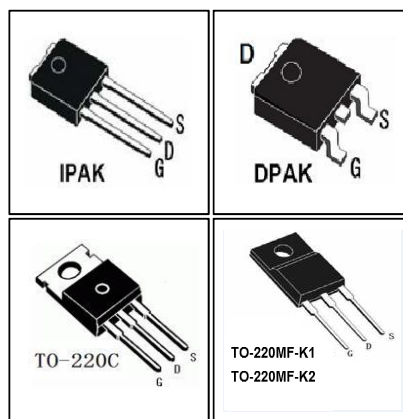
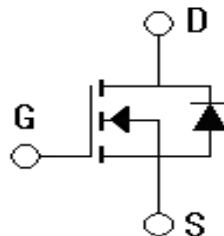
APPLICATIONS

- High efficiency switch mode power supplies
- Electronic lamp ballasts based on half bridge
- LED power supplies

FEATURES

- Low gate charge
- Low C_{rss} (typical 4.4pF)
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability
- RoHS product

封装 Package



订货信息 ORDER MESSAGE

订货型号 Order codes				印记 Marking	封装 Package
有卤-条管 Halogen-Tube	无卤-条管 Halogen-Free-Tube	有卤-编带 Halogen-Reel	无卤-编带 Halogen-Free-Reel		
N/A	MP7AN65E-V-BR	N/A	N/A	MP7AN65E	IPAK
N/A	MP7AN65E-R-BR	N/A	MP7AN65E-R-AR	MP7AN65E	DPAK
MP7AN65E-C-B	MP7AN65E-C-BR	N/A	N/A	MP7AN65E	TO-220C
MP7AN65E-F1-B	MP7AN65E-F1-BR	N/A	N/A	MP7AN65E	TO-220MF-K1
MP7AN65E-F2-B	MP7AN65E-F2-BR	N/A	N/A	MP7AN65E	TO-220MF-K2



绝对最大额定值ABSOLUTE RATINGS($T_c=25^\circ\text{C}$)

项目 Parameter	符号 Symbol	数值 Value		单位 Unit
		TO-220C/IPAK/ DPAK	TO-220MF-K1/K2	
最高漏极-源极直流电压 Drain-Source Voltage	V_{DSS}	650		V
连续漏极电流 Drain Current-continuous	I_D $T=25^\circ\text{C}$ $T=100^\circ\text{C}$	7.0	7.0*	A
		4.2	4.2*	A
最大脉冲漏极电流 (注1) Drain Current – pulse (note 1)	I_{DM}	28	28*	A
最高栅源电压 Gate-Source Voltage	V_{GSS}	± 30		V
单脉冲雪崩能量 (注2) Single Pulsed Avalanche Energy (note 2)	E_{AS}	448		mJ
雪崩电流 (注1) Avalanche Current (note 1)	I_{AS}	7.0		A
重复雪崩能量 (注1) Repetitive Avalanche Current (note 1)	E_{AR}	11.1		mJ
二极管反向恢复最大电压变化速率 (注3) Peak Diode Recovery dv/dt (note 3)	dv/dt	4.5		V/ns
耗散功率 Power Dissipation	P_D $T_C=25^\circ\text{C}$ -Derate above 25°C	120.0	30.0	W
		0.96	0.24	W/ $^\circ\text{C}$
最高结温及存储温度 Operating and Storage Temperature Range	T_J, T_{STG}	150; -55~+150		$^\circ\text{C}$
引线最高焊接温度 Maximum Lead Temperature for Soldering Purposes	T_L	300		$^\circ\text{C}$

*漏极电流由最高结温限制

*Drain current limited by maximum junction temperature



电特性 ELECTRICAL CHARACTERISTICS

项目 Parameter	符号 Symbol	测试条件 Tests conditions	最小 Min	典型 Typ	最大 Max	单位 Units
关态特性 Off –Characteristics						
漏-源击穿电压 Drain-Source Voltage	BV_{DSS}	$I_D=250\mu A, V_{GS}=0V$	650	-	-	V
击穿电压温度特性 Breakdown Voltage Temperature Coefficient	$\frac{\Delta BV_{DSS}}{\Delta T_J}$	$I_D=250\mu A$, referenced to 25°C	-	0.65	-	V/°C
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=650V, V_{GS}=0V, T_C=25^\circ C$	-	-	1	μA
		$V_{DS}=520V, V_{GS}=0V, T_C=125^\circ C$	-	-	100	μA
正向栅极体漏电流 Gate-body leakage current, forward	I_{GSSF}	$V_{DS}=0V, V_{GS}=30V$	-	-	100	nA
反向栅极体漏电流 Gate-body leakage current, reverse	I_{GSSR}	$V_{DS}=0V, V_{GS}=-30V$	-	-	-100	nA
通态特性 On-Characteristics						
阈值电压 Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D=250\mu A$	2.0	-	4.0	V
静态导通电阻 Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=3.5A$ 25°C	-	1.0	1.25	Ω
正向跨导 Forward Transconductance	g_{fs}	$V_{DS}=40V, I_D=7.0A$ (note 4)	-	5.6	-	S
动态特性 Dynamic Characteristics						
栅极电阻 Gate resistance	R_g	F=1.0MHz open drain	0.5	2.0	4.5	Ω
输入电容 Input capacitance	C_{iss}	$V_{DS}=25V,$ $V_{GS}=0V,$ $f=1.0MHz$	-	881	1800	pF
输出电容 Output capacitance	C_{oss}		-	92	200	pF
反向传输电容 Reverse transfer capacitance	C_{rss}		-	4.4	15	pF





电特性 ELECTRICAL CHARACTERISTICS

开关特性 Switching Characteristics						
延迟时间 Turn-On delay time	$t_{d(on)}$	$V_{DD}=325V, I_D=7A, R_G=25\Omega$ (note 4, 5)	-	35.2	60	ns
上升时间 Turn-On rise time	t_r		-	30.2	80	ns
延迟时间 Turn-Off delay time	$t_{d(off)}$		-	62.4	95	ns
下降时间 Turn-Off Fall time	t_f		-	12.1	30	ns
栅极电荷总量 Total Gate Charge	Q_g	$V_{DS}=520V,$ $I_D=7A$ $V_{GS}=10V$ (note 4, 5)	-	20	35	nC
栅-源电荷 Gate-Source charge	Q_{gs}		-	5.0	10	nC
栅-漏电荷 Gate-Drain charge	Q_{gd}		-	8.5	17	nC
漏-源二极管特性及最大额定值 Drain-Source Diode Characteristics and Maximum Ratings						
正向最大连续电流 Maximum Continuous Drain -Source Diode Forward Current		I_S	-	-	7	A
正向最大脉冲电流 Maximum Pulsed Drain-Source Diode Forward Current		I_{SM}	-	-	28	A
正向压降 Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS}=0V,$ $I_S=7A$	-	-	1.4	V
反向恢复时间 Reverse recovery time	t_{rr}	$V_{GS}=0V, I_S=7A$ $di/dt=100A/\mu s$ (note 4)	-	415	-	ns
反向恢复电荷 Reverse recovery charge	Q_{rr}		-	2.4	-	μC

热特性 THERMAL CHARACTERISTIC

项目 Parameter	符号 Symbol	TO-220C/IPAK/ DPAK	TO-220MF-K1/K2	单位 Unit
结到管壳的热阻 Thermal Resistance, Junction to Case	$R_{th(j-c)}$	1.04	4.16	$^{\circ}C/W$
结到环境的热阻 Thermal Resistance, Junction to Ambient	$R_{th(j-A)}$	62.5	62.5	$^{\circ}C/W$

注释:

- 1: 脉冲宽度由最高结温限制
- 2: $L=23mH, I_{AS}=7A, V_{DD}=50V, R_G=25\Omega$, 起始结温 $T_J=25^{\circ}C$
- 3: $I_{SD} \leq 7A, di/dt \leq 300A/\mu s, V_{DD} \leq BV_{DSS}$, 起始结温 $T_J=25^{\circ}C$
- 4: 脉冲测试: 脉冲宽度 $\leq 300\mu s$, 占空比 $\leq 2\%$
- 5: 基本与工作温度无关

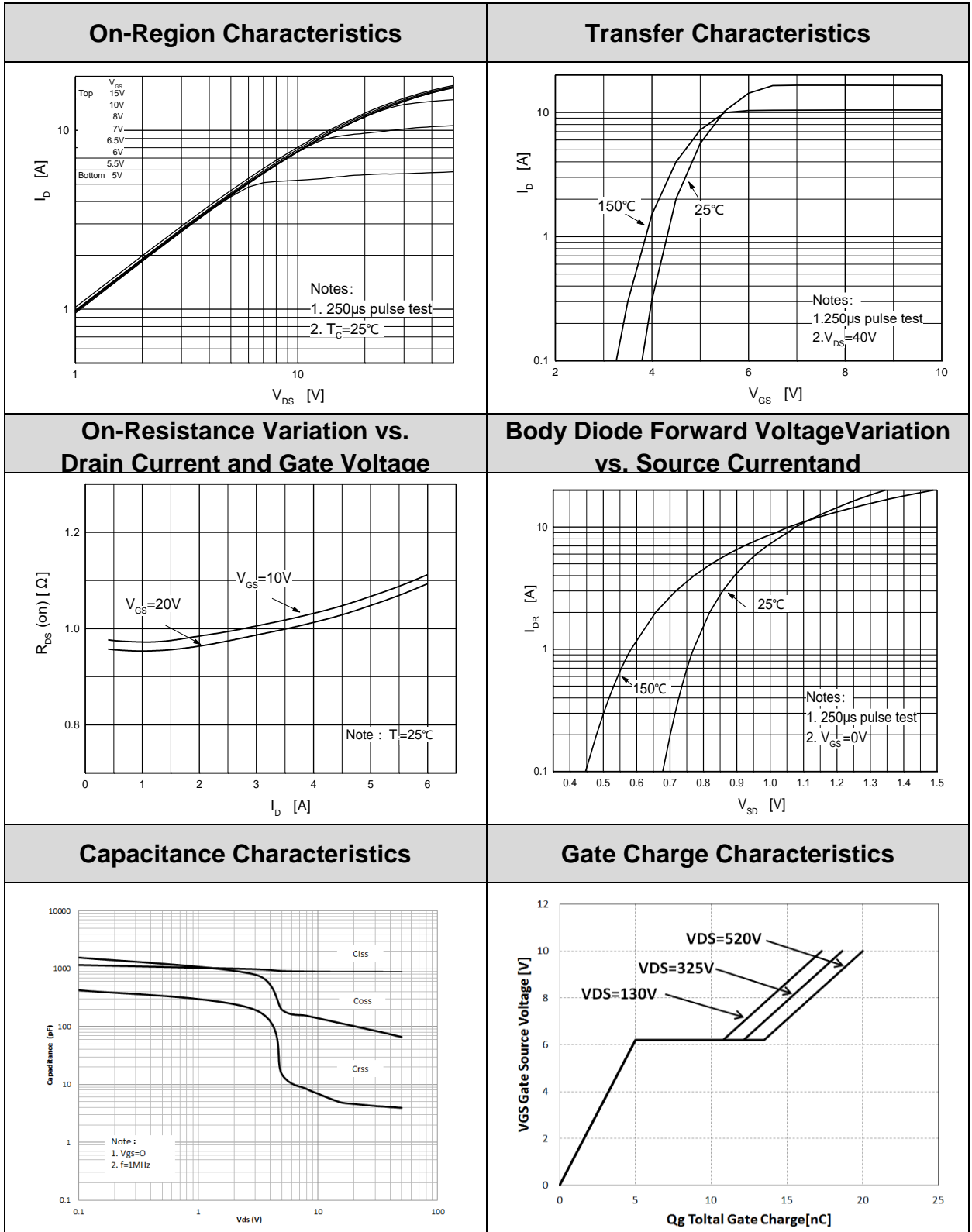
Notes:

- 1: Pulse width limited by maximum junction temperature
- 2: $L=23mH, I_{AS}=7A, V_{DD}=50V, R_G=25\Omega$, Starting $T_J=25^{\circ}C$
- 3: $I_{SD} \leq 7A, di/dt \leq 300A/\mu s, V_{DD} \leq BV_{DSS}$, Starting $T_J=25^{\circ}C$
- 4: Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycles $\leq 2\%$
- 5: Essentially independent of operating temperature



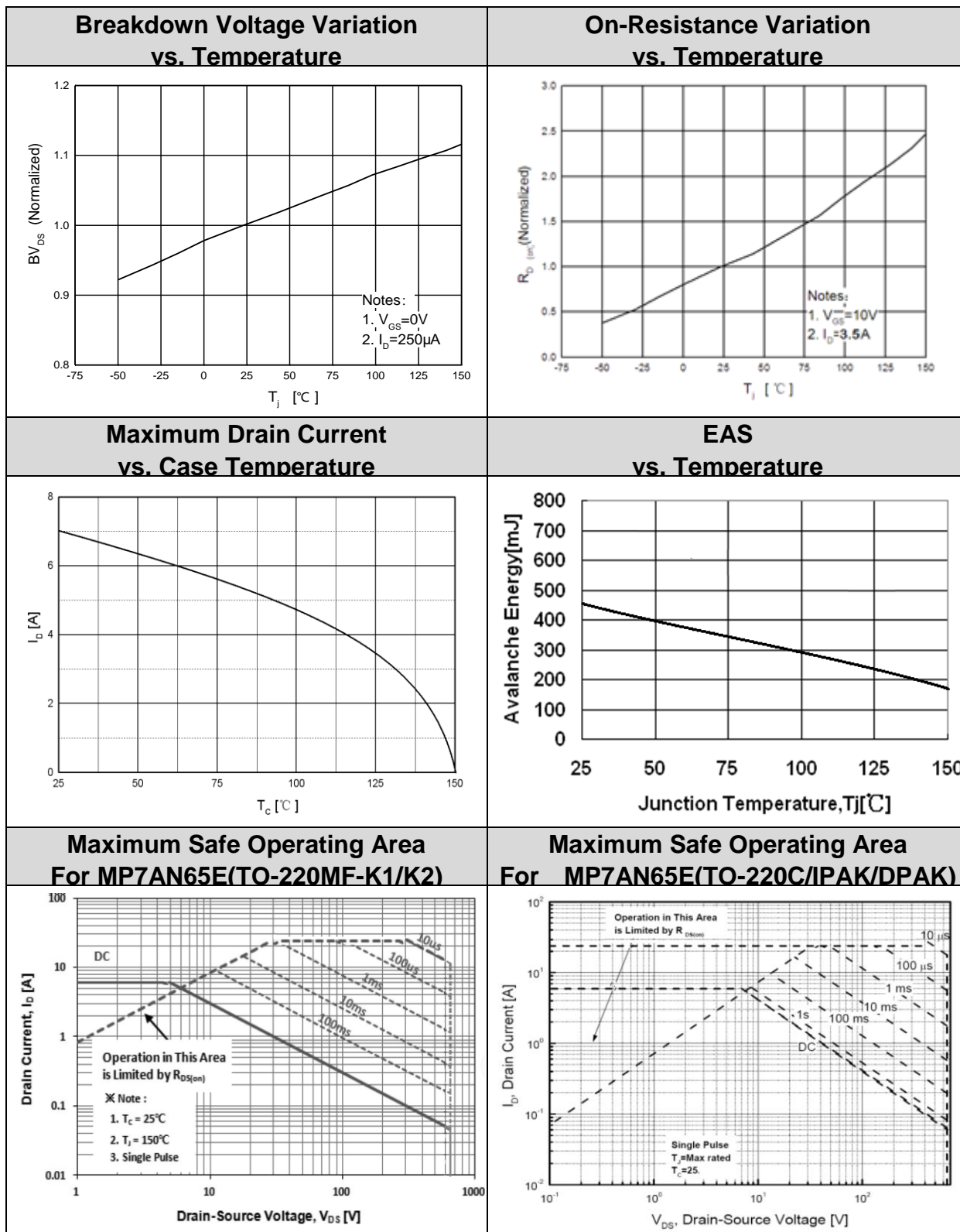


特征曲线ELECTRICAL CHARACTERISTICS (curves)



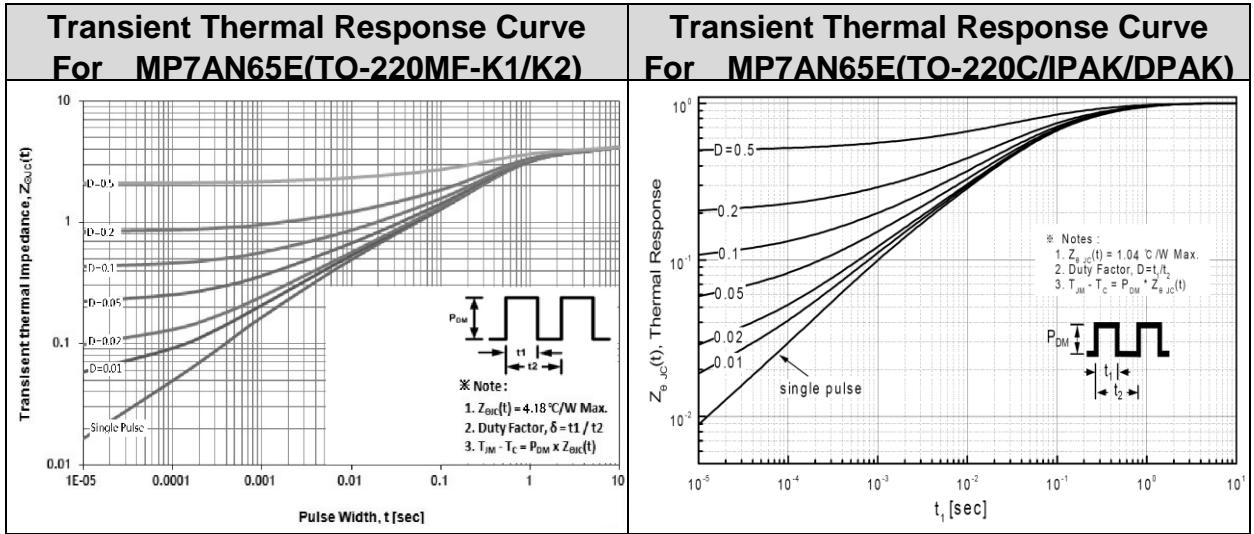


特征曲线ELECTRICAL CHARACTERISTICS (curves)





特征曲线ELECTRICAL CHARACTERISTICS (curves)

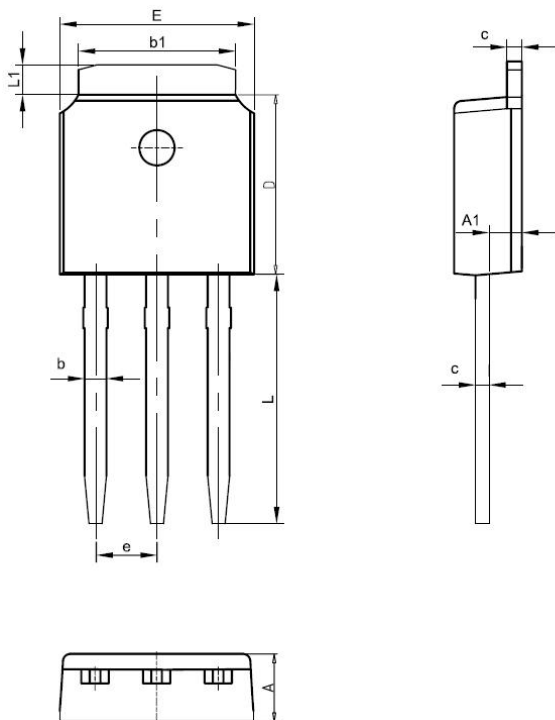




外形尺寸 PACKAGE MECHANICAL DATA

IPAK

单位 Unit: mm



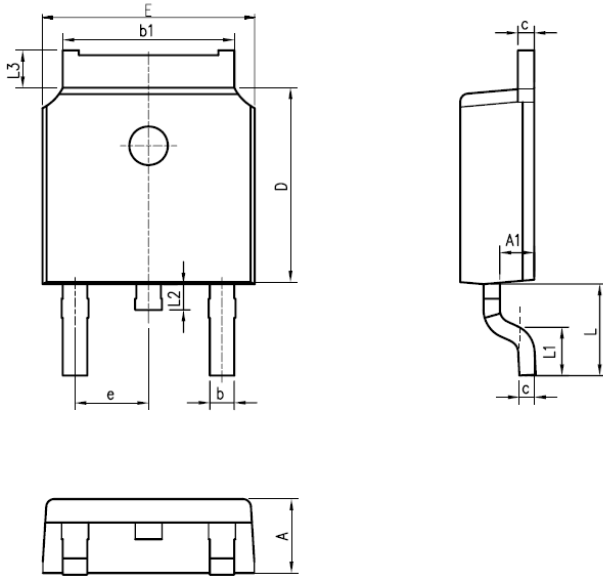
SYMBOL	MM	
	MIN	MAX
A	2.1	2.5
A1	0.87	1.27
b	0.63	0.93
b1	5.13	5.53
c	0.40	0.60
D	5.80	6.40
E	6.30	6.90
L	9.10	9.70
e	2.286BSC	
L1	0.82	1.22



外形尺寸 PACKAGE MECHANICAL DATA

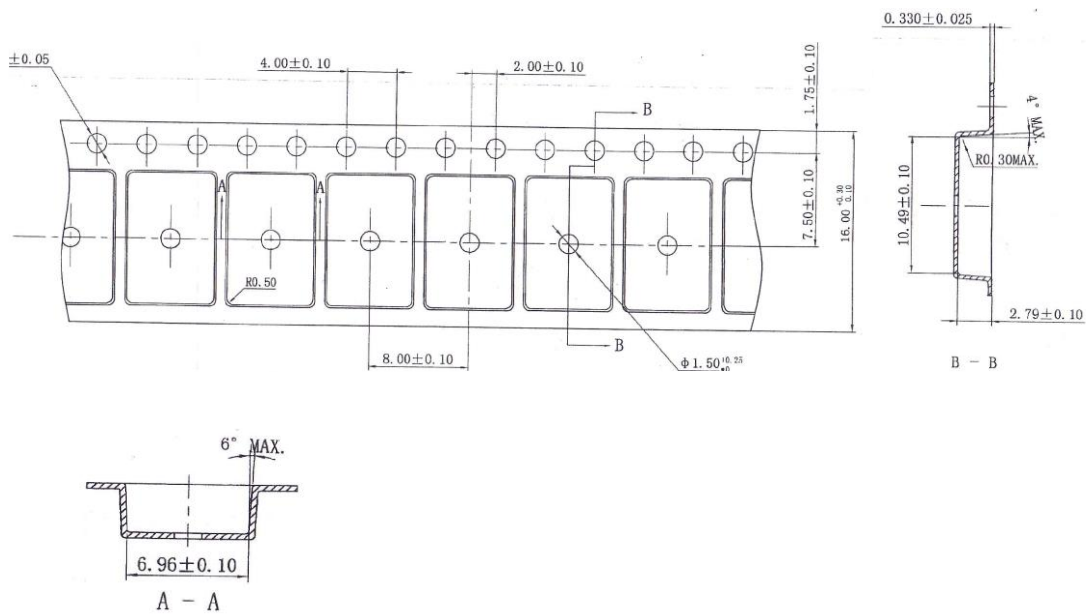
DPAK

单位 Unit: mm



SYMBOL	mm	
	MIN	MAX
A	2.10	2.50
A1	0.97	1.17
b	0.63	0.93
b1	5.13	5.53
c	0.40	0.60
D	5.80	6.40
E	6.30	6.90
e	2.286BSC	
L	2.50	3.30
L1	1.20	1.80
L2	0.60	1.00
L3	0.85	1.30

编带 REEL

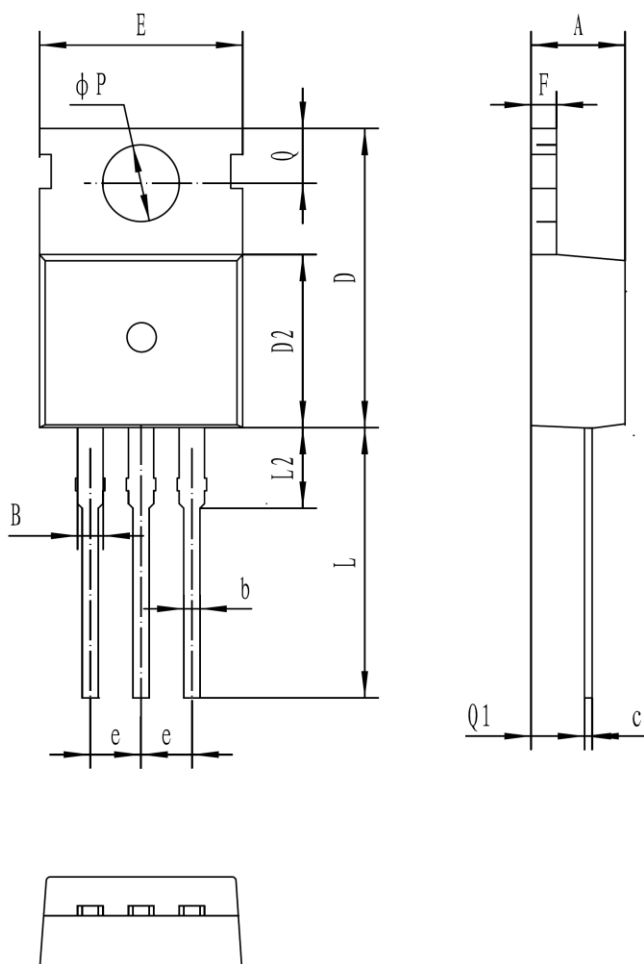




外形尺寸 PACKAGE MECHANICAL DATA

TO-220C

单位 Unit: mm



符号 symbol	MIN	MAX
A	4.30	4.70
B	1.10	1.40
b	0.70	0.95
c	0.40	0.65
D	15.20	16.20
D2	9.00	9.40
E	9.70	10.10
e	2.39	2.69
F	1.25	1.40
L	12.60	13.60
L2	2.80	3.20
Q	2.60	3.00
Q1	2.20	2.60
P	3.50	3.80

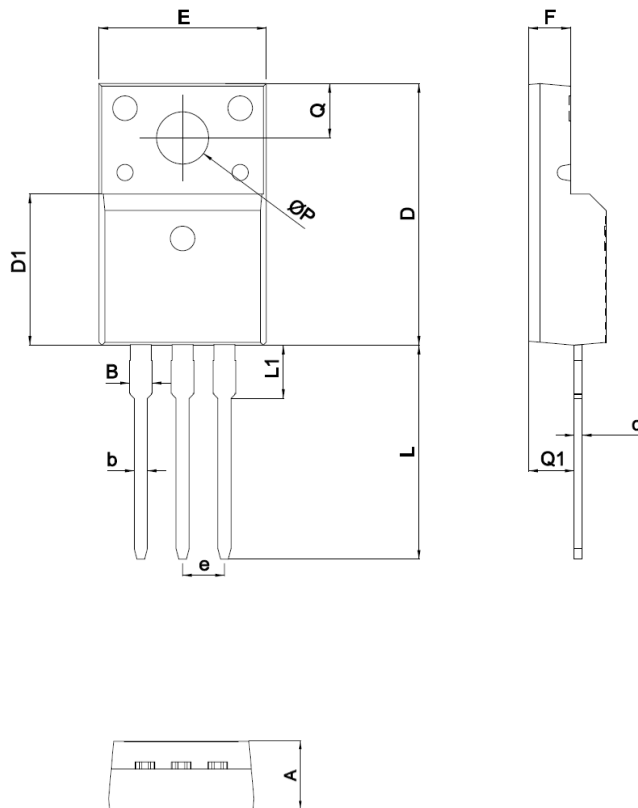




外形尺寸 PACKAGE MECHANICAL DATA

TO-220MF-K1

单位 Unit: mm



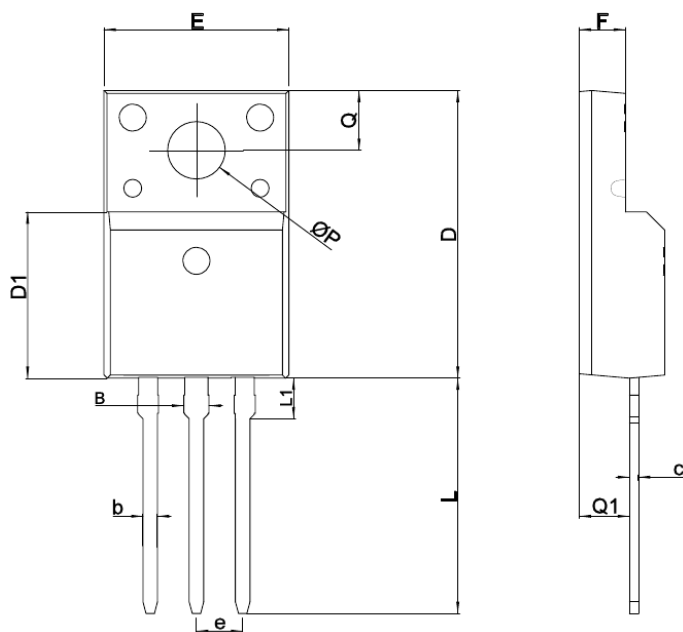
SYMBOL	mm	
	MIN	MAX
A	4.5	4.9
B	1.22	1.47
b	0.7	0.9
c	0.45	0.60
D	15.6	16.1
D1	9.0	9.3
e	2.54TYPE	
E	9.9	10.4
F	2.3	2.8
L	12.6	13.3
L1	3.1	3.4
Q	3.2	3.4
Q1	2.6	2.9
ΦP	3.0	3.5



外形尺寸 PACKAGE MECHANICAL DATA

TO-220MF-K2

单位 Unit: mm



SYMBOL	mm	
	MIN	MAX
A	4.5	4.9
B		1.27
b	0.59	0.79
c	0.45	0.60
D	15.67	16.07
D1	8.97	9.37
e	2.54TYPE	
E	9.96	10.36
F	2.34	2.74
L	12.65	13.35
L1	1.80	2.20
Q	3.2	3.4
Q1	2.56	2.96
ΦP	3.08	3.28





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